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FEATURES

Excellent Sonic Characteristics
Low Noise: $6 \text{ nV}/\sqrt{\text{Hz}}$
Low Distortion: 0.0006%
High Slew Rate: $22 \text{ V}/\mu\text{s}$
Wide Bandwidth: 9 MHz
Low Supply Current: 5 mA
Low Offset Voltage: 1 mV
Low Offset Current: 2 nA
Unity Gain Stable
SOIC-8 Package
PDIP-8 Package

APPLICATIONS

High Performance Audio
Active Filters
Fast Amplifiers
Integrators

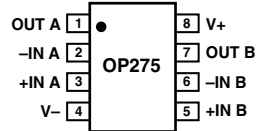
GENERAL DESCRIPTION

The OP275 is the first amplifier to feature the Butler Amplifier front end. This new front end design combines both bipolar and JFET transistors to attain amplifiers with the accuracy and low noise performance of bipolar transistors, and the speed and sound quality of JFETs. Total Harmonic Distortion plus Noise equals that of previous audio amplifiers, but at much lower supply currents.

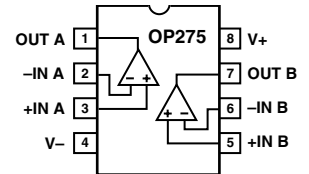
A very low $1/f$ corner of below 6 Hz maintains a flat noise density response. Whether noise is measured at either 30 Hz or 1 kHz, it is only $6 \text{ nV}/\sqrt{\text{Hz}}$. The JFET portion of the input stage gives the OP275 its high slew rates to keep distortion low, even when large output swings are required, and the $22 \text{ V}/\mu\text{s}$ slew rate of the OP275 is the fastest of any standard audio amplifier. Best of all, this low noise and high speed are accomplished using less than 5 mA of supply current, lower than any standard audio amplifier.

PIN CONNECTIONS

8-Lead Narrow-Body SOIC
(S Suffix)



8-Lead PDIP
(P Suffix)



Improved dc performance is also provided with bias and offset currents greatly reduced over purely bipolar designs. Input offset voltage is guaranteed at 1 mV and is typically less than $200 \mu\text{V}$. This allows the OP275 to be used in many dc-coupled or summing applications without the need for special selections or the added noise of additional offset adjustment circuitry.

The output is capable of driving 600Ω loads to 10 V rms while maintaining low distortion. THD + Noise at 3 V rms is a low 0.0006%.

The OP275 is specified over the extended industrial (-40°C to $+85^\circ\text{C}$) temperature range. OP275s are available in both plastic DIP and SOIC-8 packages. SOIC-8 packages are available in 2500-piece reels. Many audio amplifiers are not offered in SOIC-8 surface-mount packages for a variety of reasons; however, the OP275 was designed so that it would offer full performance in surface-mount packaging.

REV.C

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OP275* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

COMPARABLE PARTS

View a parametric search of comparable parts.

EVALUATION KITS

- EVAL-OPAMP-2 Evaluation Board

DOCUMENTATION

Application Notes

- AN-211: The Alexander Current-Feedback Audio Power Amplifier
- AN-356: User's Guide to Applying and Measuring Operational Amplifier Specifications
- AN-649: Using the Analog Devices Active Filter Design Tool

Data Sheet

- OP275: Dual Bipolar/JFET, Audio Operational Amplifier Data Sheet

TOOLS AND SIMULATIONS

- Analog Filter Wizard
- Analog Photodiode Wizard
- OP275 SPICE Macro-Model

DESIGN RESOURCES

- OP275 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

DISCUSSIONS

View all OP275 EngineerZone Discussions.

SAMPLE AND BUY

Visit the product page to see pricing options.

TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

DOCUMENT FEEDBACK

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OP275—SPECIFICATIONS

ELECTRICAL CHARACTERISTICS (@ $V_S = \pm 15.0\text{ V}$, $T_A = 25^\circ\text{C}$, unless otherwise noted.)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
AUDIO PERFORMANCE						
THD + Noise		$V_{IN} = 3\text{ V rms}$, $R_L = 2\text{ k}\Omega$, $f = 1\text{ kHz}$		0.006		%
Voltage Noise Density	e_n	$f = 30\text{ Hz}$		7		$\text{nV}/\sqrt{\text{Hz}}$
Current Noise Density	i_n	$f = 1\text{ kHz}$		6		$\text{nV}/\sqrt{\text{Hz}}$
Headroom		THD + Noise $\leq 0.01\%$, $R_L = 2\text{ k}\Omega$, $V_S = \pm 18\text{ V}$		1.5		$\text{pA}/\sqrt{\text{Hz}}$
				>12.9		dBu
INPUT CHARACTERISTICS						
Offset Voltage	V_{OS}	$-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$			1	mV
Input Bias Current	I_B	$V_{CM} = 0\text{ V}$		100	350	mV
Input Offset Current	I_{OS}	$V_{CM} = 0\text{ V}$, $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$		100	400	nA
Input Voltage Range	V_{CM}	$V_{CM} = 0\text{ V}$, $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$	-10.5		+10.5	nA
Common-Mode Rejection Ratio	CMRR	$V_{CM} = \pm 10.5\text{ V}$, $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$	80	106		nA
Large Signal Voltage Gain	A_{VO}	$R_L = 2\text{ k}\Omega$, $R_L = 2\text{ k}\Omega$, $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$, $R_L = 600\ \Omega$	250 175			nA
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$			200		nA
				2		$\mu\text{V}/^\circ\text{C}$
OUTPUT CHARACTERISTICS						
Output Voltage Swing	V_O	$R_L = 2\text{ k}\Omega$, $R_L = 2\text{ k}\Omega$, $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$, $R_L = 600\ \Omega$, $V_S = \pm 18\text{ V}$	-13.5 -13	± 13.9 ± 13.9 $+14, -16$	+13.5 +13	V
						V
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	$V_S = \pm 4.5\text{ V to } \pm 18\text{ V}$, $V_S = \pm 4.5\text{ V to } \pm 18\text{ V}$, $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$	85	111		dB
Supply Current	I_{SY}	$V_S = \pm 4.5\text{ V to } \pm 18\text{ V}$, $V_O = 0\text{ V}$, $R_L = \infty$, $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$, $V_S = \pm 22\text{ V}$, $V_O = 0\text{ V}$, $R_L = \infty$, $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$		4	5	dB
Supply Voltage Range	V_S		± 4.5		5.5 ± 22	mA
						V
DYNAMIC PERFORMANCE						
Slew Rate	SR	$R_L = 2\text{ k}\Omega$	15	22		$\text{V}/\mu\text{s}$
Full-Power Bandwidth	BW_P					kHz
Gain Bandwidth Product	GBP			9		MHz
Phase Margin	ϕ_m			62		Degrees
Overshoot Factor		$V_{IN} = 100\text{ mV}$, $A_V = +1$, $R_L = 600\ \Omega$, $C_L = 100\text{ pF}$		10		%

Specifications subject to change without notice.

ABSOLUTE MAXIMUM RATINGS¹

Supply Voltage ±22 V
 Input Voltage² ±22 V
 Differential Input Voltage² ±7.5 V
 Output Short-Circuit Duration to GND³ Indefinite
 Storage Temperature Range
 P, S Packages -65°C to +150°C
 Operating Temperature Range
 OP275G -40°C to +85°C
 Junction Temperature Range
 P, S Packages -65°C to +150°C
 Lead Temperature Range (Soldering, 60 sec) 300°C

Package Type	θ_{JA} ⁴	θ_{JC}	Unit
8-Lead Plastic DIP (P)	103	43	°C/W
8-Lead SOIC (S)	158	43	°C/W

NOTES

¹Absolute maximum ratings apply to packaged parts, unless otherwise noted.
²For supply voltages greater than ±22 V, the absolute maximum input voltage is equal to the supply voltage.
³Shorts to either supply may destroy the device. See data sheet for full details.
⁴ θ_{JA} is specified for the worst-case conditions, i.e., θ_{JA} is specified for device in socket for PDIP packages; θ_{JA} is specified for device soldered in circuit board for SOIC packages.

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option
OP275GP	-40°C to +85°C	8-Lead PDIP	N-8
OP275GS	-40°C to +85°C	8-Lead SOIC	R-8
OP275GS-REEL	-40°C to +85°C	8-Lead SOIC	R-8
OP275GS-REEL7	-40°C to +85°C	8-Lead SOIC	R-8
OP275GSZ*	-40°C to +85°C	8-Lead SOIC	R-8
OP275GSZ-REEL*	-40°C to +85°C	8-Lead SOIC	R-8
OP275GSZ-REEL7*	-40°C to +85°C	8-Lead SOIC	R-8

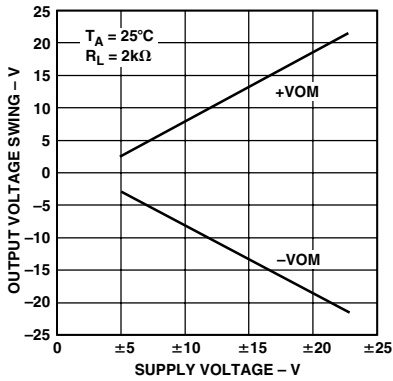
*Z = Pb-free part.

CAUTION

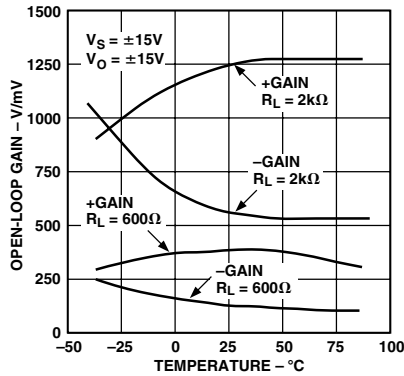
ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000V readily accumulate on the human body and test equipment and can discharge without detection. Although the OP275 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



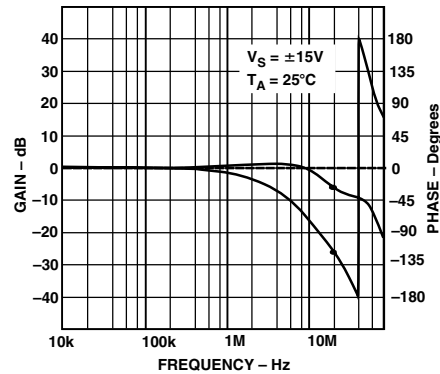
OP275—Typical Performance Characteristics



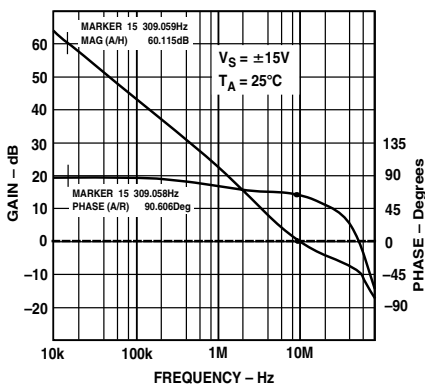
TPC 1. Output Voltage Swing vs. Supply Voltage



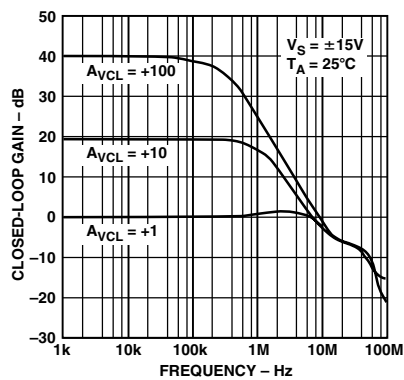
TPC 2. Open-Loop Gain vs. Temperature



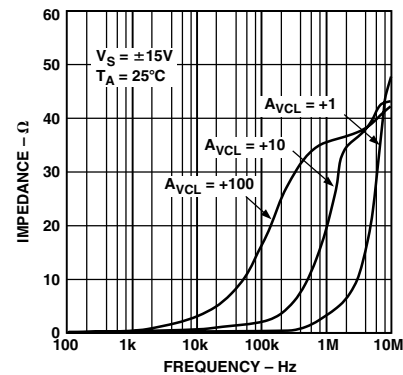
TPC 3. Closed-Loop Gain and Phase, $A_V = +1$



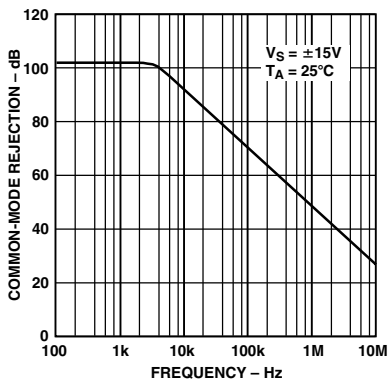
TPC 4. Open-Loop Gain, Phase vs. Frequency



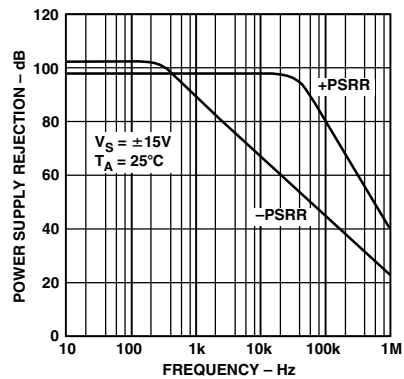
TPC 5. Closed-Loop Gain vs. Frequency



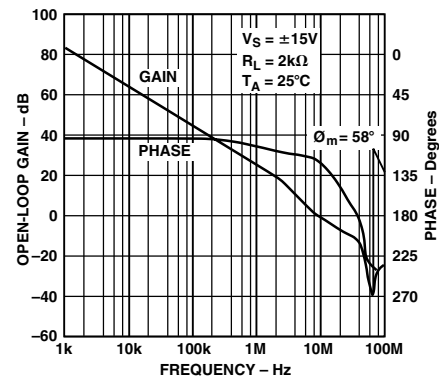
TPC 6. Closed-Loop Output Impedance vs. Frequency



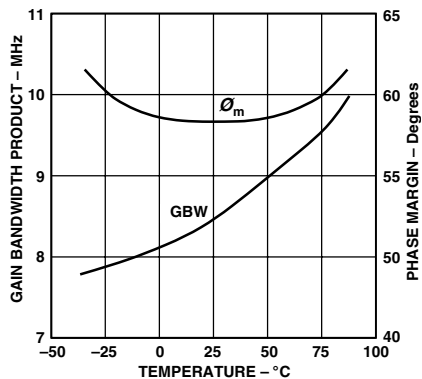
TPC 7. Common-Mode Rejection vs. Frequency



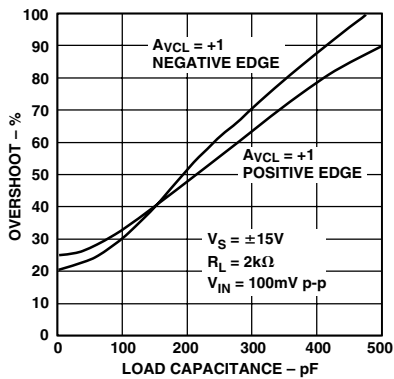
TPC 8. Power Supply Rejection vs. Frequency



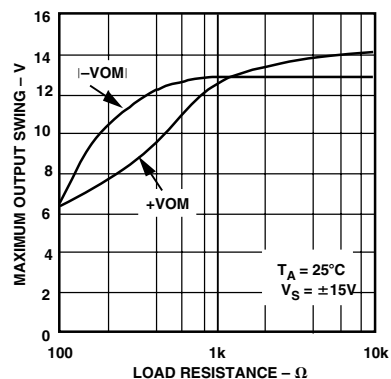
TPC 9. Open-Loop Gain, Phase vs. Frequency



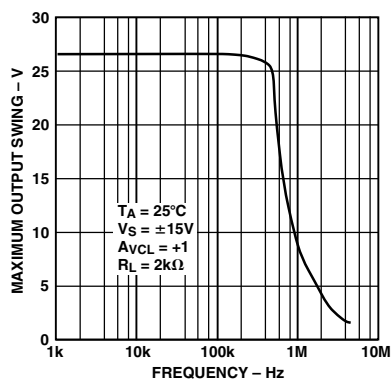
TPC 10. Gain Bandwidth Product, Phase Margin vs. Temperature



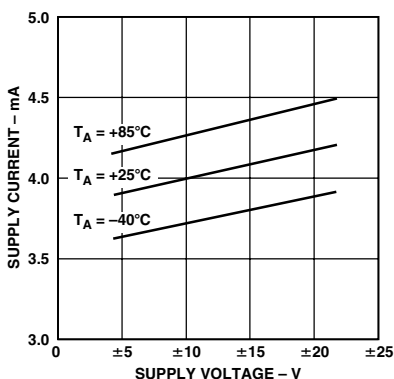
TPC 11. Small Signal Overshoot vs. Load Capacitance



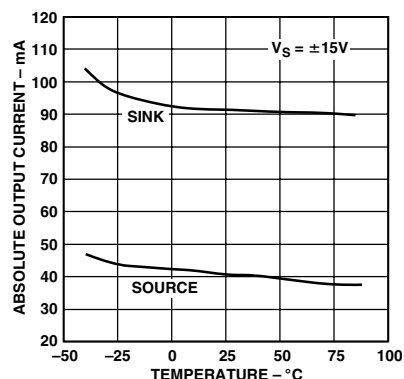
TPC 12. Maximum Output Voltage vs. Load Resistance



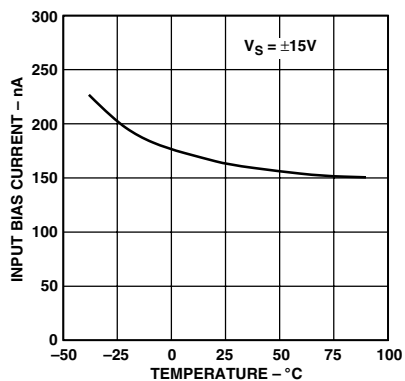
TPC 13. Maximum Output Swing vs. Frequency



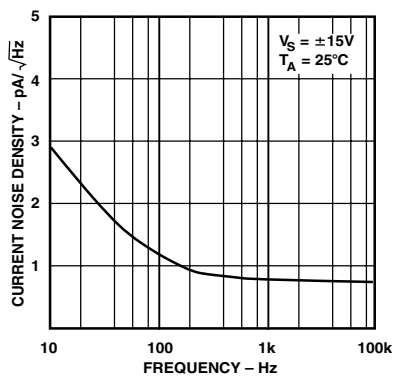
TPC 14. Supply Current vs. Supply Voltage



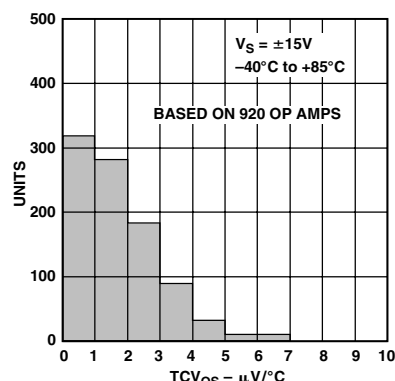
TPC 15. Short-Circuit Current vs. Temperature



TPC 16. Input Bias Current vs. Temperature

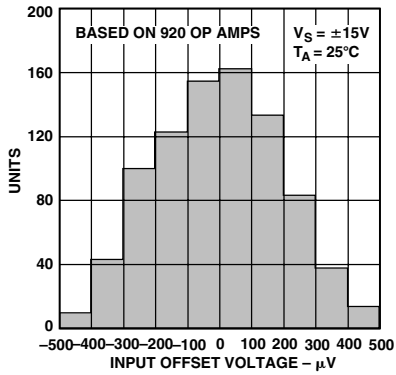


TPC 17. Current Noise Density vs. Frequency

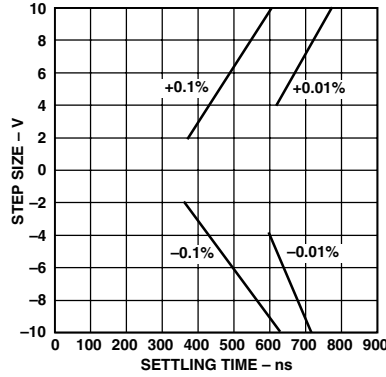


TPC 18. TCV_{OS} Distribution

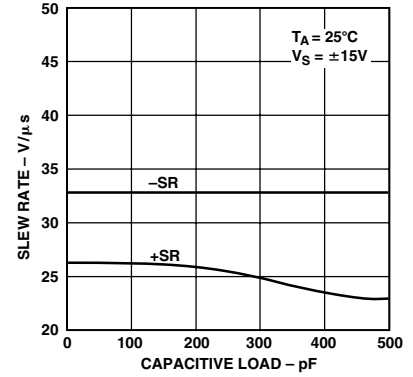
OP275



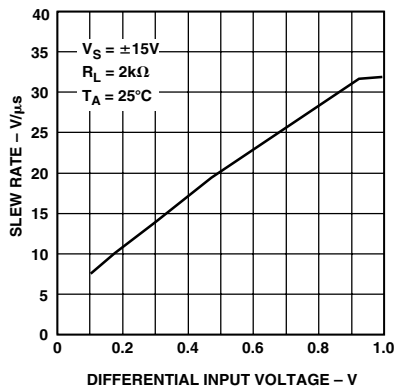
TPC 19. Input Offset (V_{OS}) Distribution



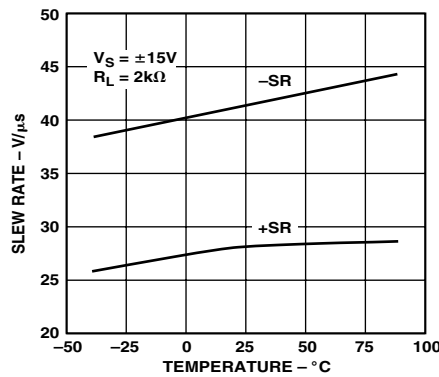
TPC 20. Step Size vs. Settling Time



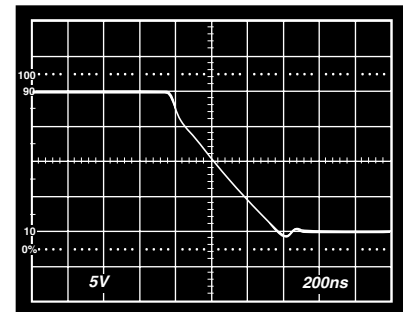
TPC 21. Slew Rate vs. Capacitive Load



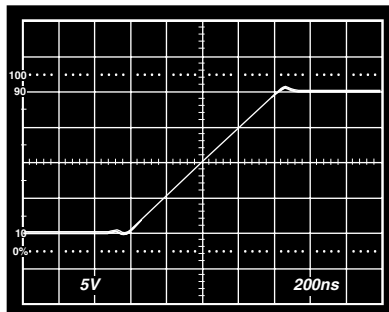
TPC 22. Slew Rate vs. Differential Input Voltage



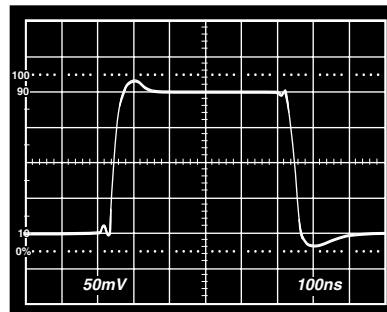
TPC 23. Slew Rate vs. Temperature



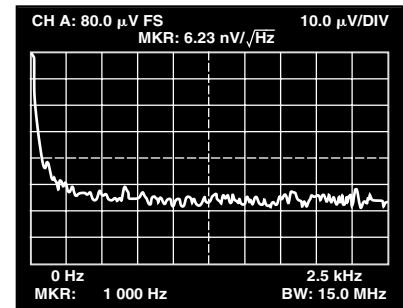
TPC 24. Negative Slew Rate
 $R_L = 2\text{ k}\Omega$, $V_S = \pm 15\text{ V}$, $A_V = +1$



TPC 25. Positive Slew Rate
 $R_L = 2\text{ k}\Omega$, $V_S = \pm 15\text{ V}$, $A_V = +1$



TPC 26. Small Signal Response
 $R_L = 2\text{ k}\Omega$, $V_S = \pm 5\text{ V}$, $A_V = +1$



TPC 27. Voltage Noise Density vs. Frequency $V_S = \pm 15\text{ V}$

APPLICATIONS

Circuit Protection

OP275 has been designed with inherent short-circuit protection to ground. An internal 30 Ω resistor, in series with the output, limits the output current at room temperature to $I_{SC+} = 40$ mA and $I_{SC-} = -90$ mA, typically, with ± 15 V supplies.

However, shorts to either supply may destroy the device when excessive voltages or currents are applied. If it is possible for a user to short an output to a supply for safe operation, the output current of the OP275 should be design-limited to ± 30 mA, as shown in Figure 1.

Total Harmonic Distortion

Total Harmonic Distortion + Noise (THD + N) of the OP275 is well below 0.001% with any load down to 600 Ω. However, this is dependent upon the peak output swing. In Figure 2, the THD + Noise with 3 V rms output is below 0.001%. In Figure 3, THD + Noise is below 0.001% for the 10 kΩ and 2 kΩ loads but increases to above 0.1% for the 600 Ω load condition. This is a result of the output swing capability of the OP275. Notice the results in Figure 4, showing THD versus V_{IN} (V rms). This figure shows that the THD + Noise remains very low until the output reaches 9.5 V rms. This performance is similar to competitive products.

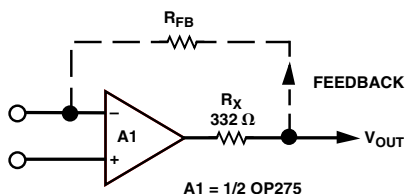


Figure 1. Recommended Output Short-Circuit Protection

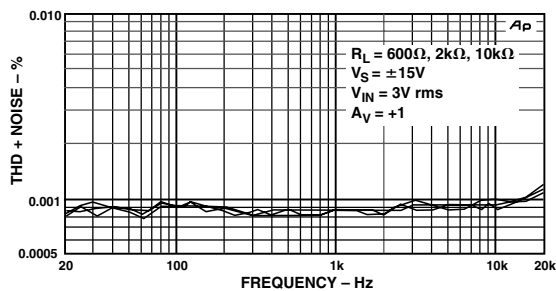


Figure 2. THD + Noise vs. Frequency vs. R_{LOAD}

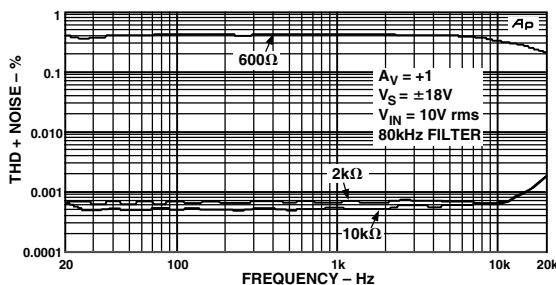


Figure 3. THD + Noise vs. R_{LOAD} ; $V_{IN} = 10$ V rms

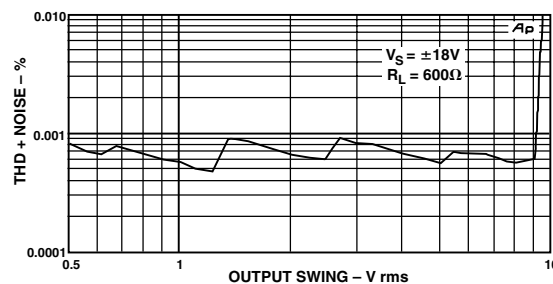


Figure 4. Headroom, THD + Noise vs. Output Amplitude (V rms); $R_{LOAD} = 600$ Ω, $V_{SUP} = \pm 18$ V

The output of the OP275 is designed to maintain low harmonic distortion while driving 600 Ω loads. However, driving 600 Ω loads with very high output swings results in higher distortion if clipping occurs. A common example of this is in attempting to drive 10 V rms into any load with ± 15 V supplies. Clipping will occur and distortion will be very high. To attain low harmonic distortion with large output swings, supply voltages may be increased. Figure 5 shows the performance of the OP275 driving 600 Ω loads with supply voltages varying from ± 18 V to ± 20 V. Notice that with ± 18 V supplies the distortion is fairly high, while with ± 20 V supplies it is a very low 0.0007%.

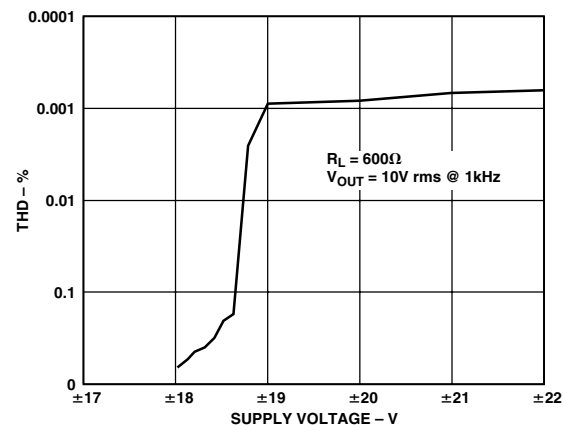


Figure 5. THD + Noise vs. Supply Voltage

Noise

The voltage noise density of the OP275 is below 7 nV/ $\sqrt{\text{Hz}}$ from 30 Hz. This enables low noise designs to have good performance throughout the full audio range. Figure 6 shows a typical OP275 with a 1/f corner at 2.24 Hz.

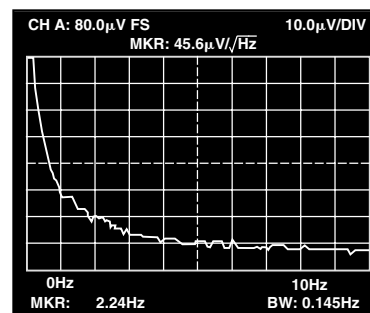


Figure 6. 1/f Noise Corner, $V_S = \pm 15$ V, $A_V = 1000$

OP275

Noise Testing

For audio applications, the noise density is usually the most important noise parameter. For characterization, the OP275 is tested using an Audio Precision, System One. The input signal to the Audio Precision must be amplified enough to measure it accurately. For the OP275, the noise is gained by approximately 1020 using the circuit shown in Figure 7. Any readings on the Audio Precision must then be divided by the gain. In implementing this test fixture, good supply bypassing is essential.

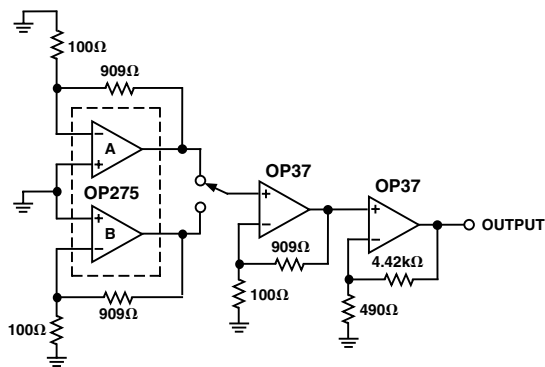


Figure 7. Noise Test Fixture

Input Overcurrent Protection

The maximum input differential voltage that can be applied to the OP275 is determined by a pair of internal Zener diodes connected across its inputs. They limit the maximum differential input voltage to ± 7.5 V. This is to prevent emitter-base junction breakdown from occurring in the input stage of the OP275 when very large differential voltages are applied. However, to preserve the OP275's low input noise voltage, internal resistances in series with the inputs were not used to limit the current in the clamp diodes. In small signal applications, this is not an issue; however, in applications where large differential voltages can be inadvertently applied to the device, large transient currents can flow through these diodes. Although these diodes have been designed to carry a current of ± 5 mA, external resistors as shown in Figure 8 should be used in the event that the OP275's differential voltage were to exceed ± 7.5 V.

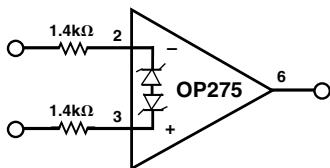


Figure 8. Input Overcurrent Protection

Output Voltage Phase Reversal

Since the OP275's input stage combines bipolar transistors for low noise and p-channel JFETs for high speed performance, the output voltage of the OP275 may exhibit phase reversal if either of its inputs exceeds its negative common-mode input voltage. This might occur in very severe industrial applications where a sensor or system fault might apply very large voltages on the inputs of the OP275. Even though the input voltage range of the OP275 is ± 10.5 V, an input voltage of approximately -13.5 V will cause output voltage phase reversal. In inverting amplifier configurations, the OP275's internal 7.5 V input clamping diodes will

prevent phase reversal; however, they will not prevent this effect from occurring in noninverting applications. For these applications, the fix is a simple one and is illustrated in Figure 9. A 3.92 k Ω resistor in series with the noninverting input of the OP275 cures the problem.

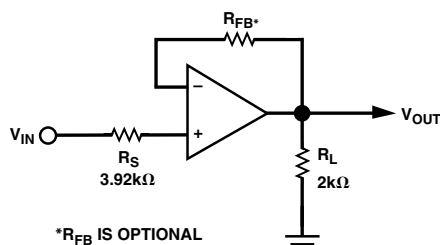


Figure 9. Output Voltage Phase Reversal Fix

Overload or Overdrive Recovery

Overload or overdrive recovery time of an operational amplifier is the time required for the output voltage to recover to a rated output voltage from a saturated condition. This recovery time is important in applications where the amplifier must recover quickly after a large abnormal transient event. The circuit shown in Figure 10 was used to evaluate the OP275's overload recovery time. The OP275 takes approximately 1.2 ms to recover to $V_{OUT} = +10$ V and approximately 1.5 μ s to recover to $V_{OUT} = -10$ V.

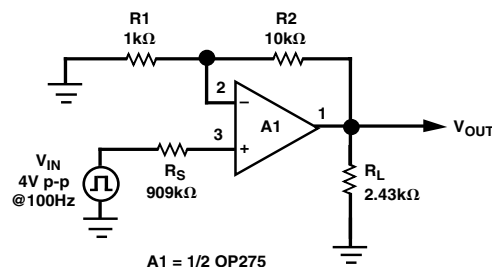


Figure 10. Overload Recovery Time Test Circuit

Measuring Settling Time

The design of OP275 combines a high slew rate and a wide gain bandwidth product to produce a fast settling ($t_s < 1$ μ s) amplifier for 8- and 12-bit applications. The test circuit designed to measure the settling time of the OP275 is shown in Figure 11. This test method has advantages over false-sum node techniques in that the actual output of the amplifier is measured, instead of an error voltage at the sum node. Common-mode settling effects are exercised in this circuit in addition to the slew rate and bandwidth effects measured by the false-sum node method. Of course, a reasonably flat-top pulse is required as the stimulus.

The output waveform of the OP275 under test is clamped by Schottky diodes and buffered by the JFET source follower. The signal is amplified by a factor of 10 by the OP260 and then Schottky-clamped at the output to prevent overloading the oscilloscope's input amplifier. The OP41 is configured as a fast integrator, which provides overall dc offset nulling.

High Speed Operation

As with most high speed amplifiers, care should be taken with supply decoupling, lead dress, and component placement. Recommended circuit configurations for inverting and noninverting applications are shown in Figures 12 and 13.

OP275

and dc offset errors. If the parallel combination of R_F and R_G is larger than $2\text{ k}\Omega$, then an additional resistor, R_S , should be used in series with the noninverting input. The value of R_S is determined by the parallel combination of R_F and R_G to maintain the low distortion performance of the OP275.

Driving Capacitive Loads

The OP275 was designed to drive both resistive loads to $600\ \Omega$ and capacitive loads of over 1000 pF and maintain stability. While there is a degradation in bandwidth when driving capacitive loads, the designer need not worry about device stability. The graph in Figure 16 shows the 0 dB bandwidth of the OP275 with capacitive loads from 10 pF to 1000 pF .

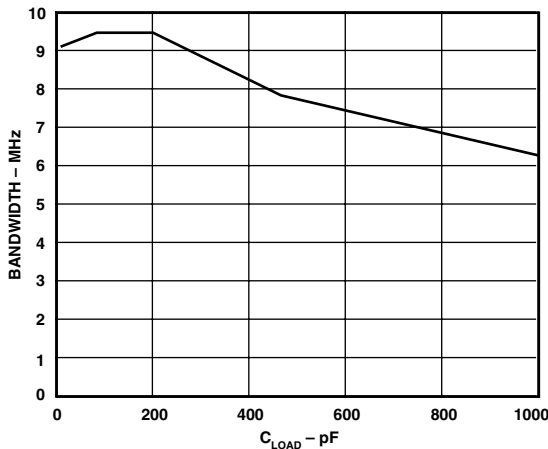


Figure 16. Bandwidth vs. C_{LOAD}

High Speed, Low Noise Differential Line Driver

The circuit in Figure 17 is a unique line driver widely used in industrial applications. With $\pm 18\text{ V}$ supplies, the line driver can deliver a differential signal of 30 V p-p into a $2.5\text{ k}\Omega$ load. The high slew rate and wide bandwidth of the OP275 combine to yield a full power bandwidth of 130 kHz while the low noise front end produces a referred-to-input noise voltage spectral density of $10\text{ nV}/\sqrt{\text{Hz}}$.

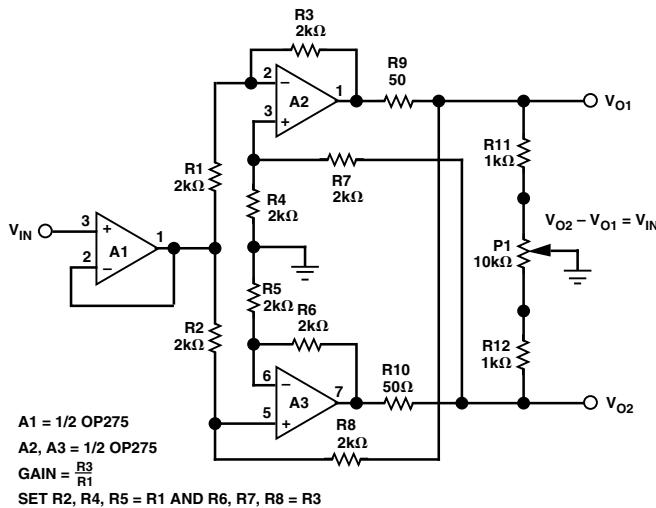


Figure 17. High Speed, Low Noise Differential Line Driver

The design is a transformerless, balanced transmission system where output common-mode rejection of noise is of paramount importance. Like the transformer based design, either output can be shorted to ground for unbalanced line driver applications without changing the circuit gain of 1. Other circuit gains can be set according to the equation in the diagram. This allows the design to be easily set to noninverting, inverting, or differential operation.

A 3-Pole, 40 kHz Low-Pass Filter

The closely matched and uniform ac characteristics of the OP275 make it ideal for use in GIC (Generalized Impedance Converter) and FDNR (Frequency-Dependent Negative Resistor) filter applications. The circuit in Figure 18 illustrates a linear-phase, 3-pole, 40 kHz low-pass filter using an OP275 as an inductance simulator (gyrator). The circuit uses one OP275 (A2 and A3) for the FDNR and one OP275 (A1 and A4) as an input buffer and bias current source for A3. Amplifier A4 is configured in a gain of 2 to set the pass band magnitude response to 0 dB . The benefits of this filter topology over classical approaches are that the op amp used in the FDNR is not in the signal path and that the filter's performance is relatively insensitive to component variations. Also, the configuration is such that large signal levels can be handled without overloading any of the filter's internal nodes. As shown in Figure 19, the OP275's symmetric slew rate and low distortion produce a clean, well behaved transient response.

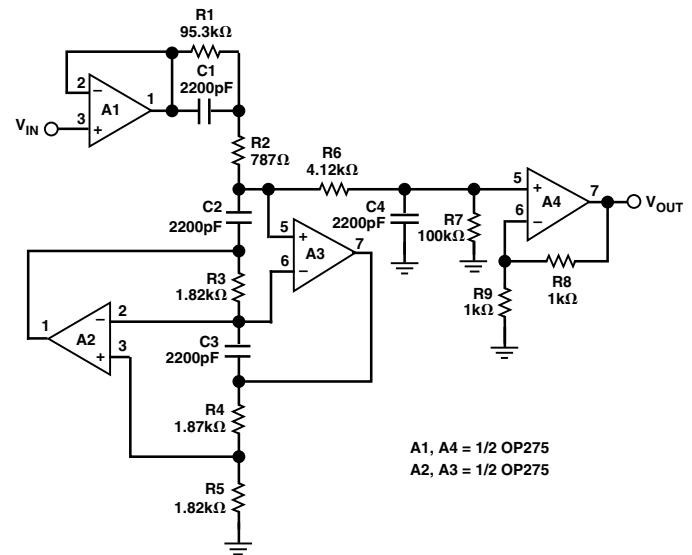


Figure 18. A 3-Pole, 40 kHz Low-Pass Filter

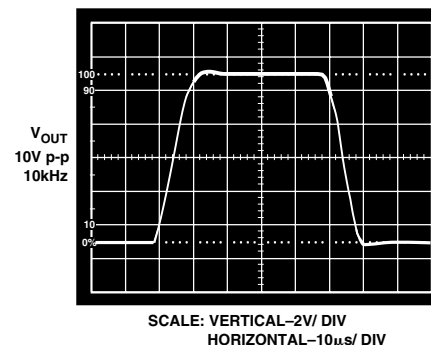


Figure 19. Low-Pass Filter Transient Response

OP275 SPICE Model

```

*
* Node assignments
*      noninverting input
*      inverting input
*      positive supply
*      negative supply
*      output
**
.SUBCKT OP275 1 2 99 50 34
*
* INPUT STAGE & POLE AT 100 MHz
*
R3 5 51 2.188
R4 6 51 2.188
CIN 1 2 3.7E-12
CM1 1 98 7.5E-12
CM2 2 98 7.5E-12
C2 5 6 364E-12
I1 97 4 100E-3
IOS 1 2 1E-9
EOS 9 3 POLY(1) 26 28 0.5E-3 1
Q1 5 2 7 QX
Q2 6 9 8 QX
R5 7 4 1.672
R6 8 4 1.672
D1 2 36 DZ
D2 1 36 DZ
EN 3 1 10 0 1
GN1 0 2 13 0 1E-3
GN2 0 1 16 0 1E-3
*
EREF 98 0 28 0 1
EP 97 0 99 0 1
EM 51 0 50 0 1
*
* VOLTAGE NOISE SOURCE
*
DN1 35 10 DEN
DN2 10 11 DEN
VN1 35 0 DC 2
VN2 0 11 DC 2
*
* CURRENT NOISE SOURCE
*
DN3 12 13 DIN
DN4 13 14 DIN
VN3 12 0 DC 2
VN4 0 14 DC 2
*
* CURRENT NOISE SOURCE
*
DN5 15 16 DIN
DN6 16 17 DIN
VN5 15 0 DC 2
VN6 0 17 DC 2
*
* GAIN STAGE & DOMINANT POLE AT 32 Hz
*
R7 18 98 1.09E6
C3 18 98 4.55E-9
G1 98 18 5 6 4.57E-1
V2 97 19 1.35
V3 20 51 1.35
D3 18 19 DX
D4 20 18 DX

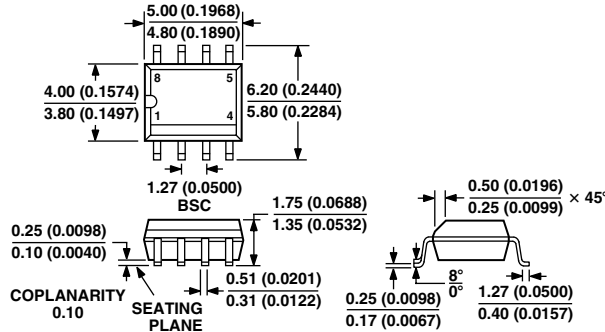
* POLE/ZERO PAIR AT 1.5 MHz/2.7 MHz
*
R8 21 98 1E-3
R9 21 22 1.25E-3
C4 22 98 47.2E-12
G2 98 21 18 28 1E-3
*
* POLE AT 100 MHz
*
R10 23 98 1
C5 23 98 1.59E-9
G3 98 23 21 28 1
*
* POLE AT 100 MHz
*
R11 24 98 1
C6 24 98 1.59E-9
G4 98 24 23 28 1
*
* COMMON-MODE GAIN NETWORK WITH ZERO AT
1 kHz
*
R12 25 26 1E6
C7 25 26 1.5915E-12
R13 26 98 1
E2 25 98 POLY(2) 1 98 2 98 0 2.50
*
* POLE AT 100 MHz
*
R14 27 98 1
C8 27 98 1.59E-9
G5 98 27 24 28 1
*
* OUTPUT STAGE
*
R15 28 99 100E3
R16 28 50 100E3
C9 28 50 1E-6
ISY 99 50 1.85E-3
R17 29 99 100
R18 29 50 100
L2 29 34 1E-9
G6 32 50 27 29 10E-3
G7 33 50 29 27 10E-3
G8 29 99 99 27 10E-3
G9 50 29 27 50 10E-3
V4 30 29 1.3
V5 29 31 3.8
F1 29 0 V4 1
F2 0 29 V5 1
D5 27 30 DX
D6 31 27 DX
D7 99 32 DX
D8 99 33 DX
D9 50 32 DY
D10 50 33 DY
*
* MODELS USED
*
.MODEL QX PNP(BF=5E5)
.MODEL DX D(IS=1E-12)
.MODEL DY D(IS=1E-15 BV=50)
.MODEL DZ D(IS=1E-15 BV=7.0)
.MODEL DEN D(IS=1E-12 RS=4.35K KF=1.95E-15
AF=1)
.MODEL DIN D(IS=1E-12 RS=268 KF=1.08E-15 AF=1)
.ENDS

```

OUTLINE DIMENSIONS

8-Lead Standard Small Outline Package [SOIC]
(S Suffix)
(R-8)

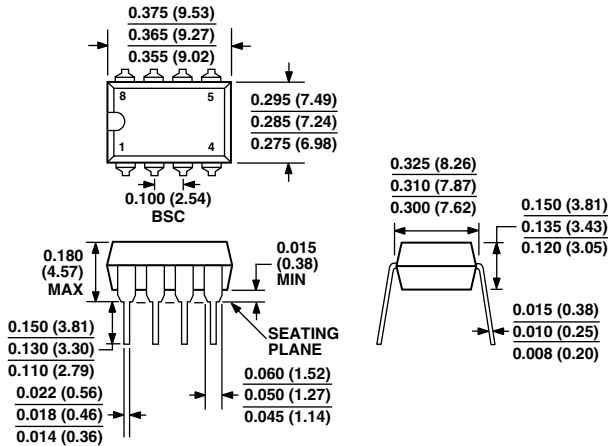
Dimensions shown in millimeters and (inches)



COMPLIANT TO JEDEC STANDARDS MS-012AA
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS
(IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR
REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN

8-Lead Plastic Dual-in-Line Package [PDIP]
(P Suffix)
(N-8)

Dimensions shown in inches and (millimeters)



COMPLIANT TO JEDEC STANDARDS MO-095AA
CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS
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Revision History

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Updated OUTLINE DIMENSIONS	12
1/03—Data Sheet changed from REV. A to REV. B.	
Deleted WAFER TEST LIMITS	3
Edits to ABSOLUTE MAXIMUM RATINGS	3
Edits to ORDERING GUIDE	3
Deleted DICE CHARACTERISTICS	3
Updated OUTLINE DIMENSIONS	12